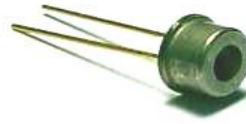


# UV-A Sensor

## GUVA-T11GD-L

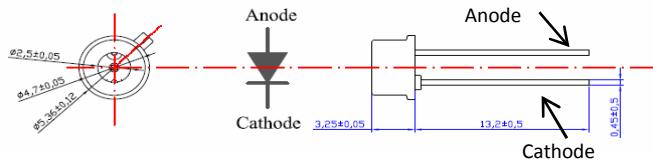
Genuine UV Technology  
**GenUV**

<b>Features</b>	Gallium Nitride Based Material Schottky-type Photodiode Photovoltaic Mode Operation Good Visible Blindness High Responsivity & Low Dark Current
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<b>Applications</b>	Full UV Band Monitoring UV-A Lamp Monitoring
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### Outline Diagrams and Dimensions



### Absolute Maximum Ratings

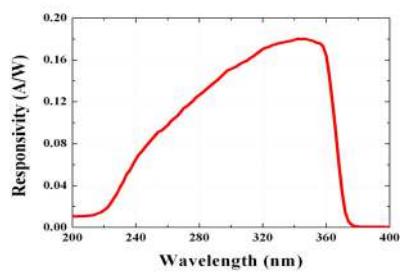
Parameter	Symbol	Min.	Max.	Unit	Remark
Storage Temperature	T <sub>st</sub>	-40	90	°C	
Operating Temperature	T <sub>op</sub>	-30	85	°C	
Reverse Voltage	V <sub>r, max.</sub>		5	V	
Forward Current	I <sub>f,max.</sub>		1	mA	
Optical Source Power Range	P <sub>opt</sub>	0.01μ	100m	W/cm <sup>2</sup>	UVA Lamp
Soldering Temperature	T <sub>sol</sub>		260	°C	within 10 sec.

※Notice: apply to us in the case that Optical Source Power is over 100mW/cm<sup>2</sup>

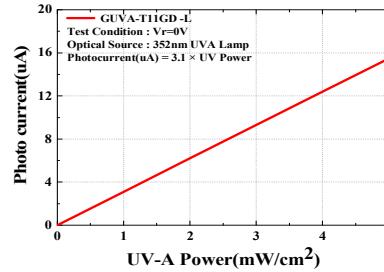
### Characteristics (at 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Dark Current	I <sub>d</sub>			20	nA	V <sub>r</sub> = 0.1 V
Photo Current	I <sub>ph</sub>	2.8	3.1	3.4	μA	UVA Lamp, 1mW/cm <sup>2</sup>
Temperature Coefficient	I <sub>tc</sub>		0.05		%/°C	UVA Lamp
Responsivity	R		0.18		A/W	λ = 350 nm, V <sub>r</sub> = 0 V
Spectral Detection Range	λ	220		370	nm	10% of R
Active area			1.536		mm <sup>2</sup>	

### Responsivity Curve



### Photocurrent along UV Power



### Caution

ESD can damage the device hence please avoid ESD. Insulate the cap of TO-CAN or it can cause malfunction of the device.